Electronic Supplementary Information

Layered VSe₂: A promising host for fast zinc storage and its working mechanism

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Figure S1. (a) High-resolution V 2p and (b) Se 3d XPS spectrum of VSe₂.



Figure S2. The XRD pattern of VSe₂ electrode after electrode fabrication.



Figure S3. The SEM images of VSe₂ electrode material after electrode fabrication.



Figure S4. The charge/discharge profiles of Zn/VSe₂ battery at different current densities.



Figure S5. Ex situ XRD patterns at different charge/discharge states, in which the diffraction peaks of Se and $Zn_4SO_4(OH)_6 \cdot 5H_2O$ can be clearly observed.



Figure S6. The SEM images of VSe₂ electrodes (a-b) after 20 cycles (c-d) and 50 cycles.



Figure S7. (a) V 2p, (b) O 1s and (c) Zn 2p XPS spectra in different states of VSe₂.

Samples	Voltage Window	Electrolyte	Specific capacity		Cycling performnace			Rate performance		Ref.
	(V)		Current	Capacity	Current	Cvcle	Capacity	Current	Capacity	-
			(mA g-1)	(mAh g ⁻¹)	(mA g ⁻¹)	number	retention	(mA g-1)	(mAh g ⁻¹)	
BL-	0.3-1.5	0.5M AN-	14.4	196	14.4	120	87%	288	130	1
V ₂ O ₅		Zn(TFI) ₂								
V ₂ O ₅	0.4-1.4	3M	100	224	2000	400	/	2000	113	2
		ZnSO ₄								
V ₂ O ₅	0.5-1.5	3M	20	319	588	500	81%	2940	104	3
		Zn(CF ₃ SO								
		3)2								
Mg _{0.34} V	0.1-1.8	3M	50	353	5000	2000	97%	5000	81	4
$_2O_5 \cdot nH_2$		Zn(CF ₃ SO								
0		3)2								
VS ₂	0.4-1.0	1M	50	190.3	500	200	98%	2000	115.5	5
		ZnSO ₄								
MoS ₂	0.3-1.5	2M	100	202.6	1000	600	98.6	4000	104.5	6
		ZnSO ₄								
MoS ₂ -O	0.2-1.4	3M	100	232	1000	2000	68%	1000	98	7
		Zn(CF ₃ SO								
		3)2								
MoS _{2-x}	0.25-	3M	100	135	1000	1000	87.8%	2000	80.8	8
	1.25	Zn(CF ₃ SO								
		3)2								
α-MnO ₂	1.0-1.8	1M	83	233	83	50	63%	1666	226	9
		ZnSO ₄								
δ-MnO ₂	1.0-1.8	1M	83	250	83	100	44%	1666	7	10
		ZnSO ₄								
Todorok	0.7-2.0	1M	50	108	50	50	50%	1000	39.6	11
ite-type		ZnSO ₄								
MnO ₂										

Table S1. Comparison of the Zn ion storage performance of VSe_2 and other recently reportedZn-ion battery cathodes.

MnO ₂ @	1.0-1.8	1M	66	272	66	50	69%	/	/	12
С		ZnSO ₄								
ZnMn ₂	0.8-1.9	3M	50	150	500	500	94%	/	/	13
O ₄		Zn(CF ₃ SO								
		3)2								
Zn ₃ V ₂ O	0.2-1.8	1M	50	213	200	300	68%	3000	54	14
7(OH) [.]		ZnSO ₄								
2H ₂ O										
Na ₃ V ₂ (P	0.8-1.7	0.5M	50	93	50	200	77%	2000	60	15
O ₄) ₃		CH ₃ COO								
		Na								
		+Zn(CH ₃								
		COO) ₂								
This	0.1-1.6	2M	200	250.6	2000	800	83%	5000	132.6	/
work		ZnSO ₄								

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